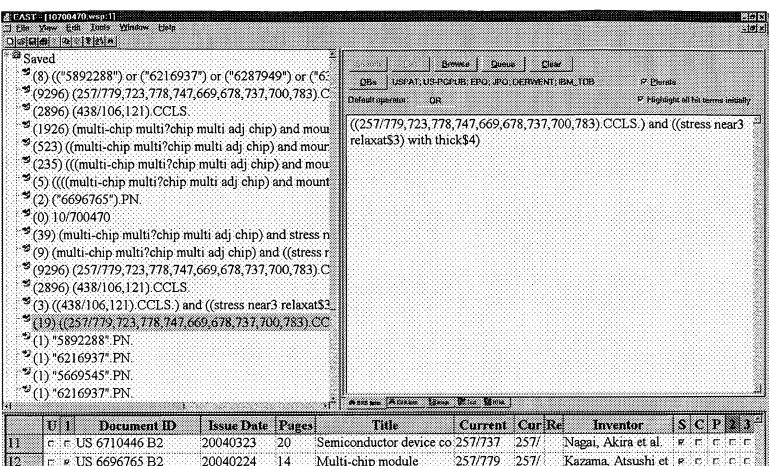
L Number	Hits	Search Text	DB	Time stamp
-	8	(("5892288") or ("6216937") or ("6287949") or ("6301121")).PN.	USPAT;	2004/03/25 16:45
			US-PGPUB;	
			ЕРО; ЛРО;	
			DERWENT;	
			IBM_TDB	
-	9296	(257/779,723,778,747,669,678,737,700,783).CCLS.	USPAT;	2004/03/26 05:17
			US-PGPUB;	
			ЕРО; ЈРО;	
			DERWENT;	
			IBM_TDB	
-	2896	(438/106,121).CCLS.	USPAT;	2004/03/26 05:17
			US-PGPUB;	
			ЕРО; ЈРО;	
			DERWENT;	
			IBM_TDB	
_	1926	(multi-chip multi?chip multi adj chip) and mount\$3 near3 board	USPAT;	2004/03/26 05:08
			US-PGPUB;	
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			DERWENT,	
			IBM_TDB	
_	523	((multi-chip multi?chip multi adj chip) and mount\$3 near3 board) and	USPĀT;	2004/03/25 16:48
		electrode	US-PGPUB,	
			ЕРО; ЛРО;	
			DERWENT;	
		·	IBM_TDB	•
_	235	(((multi-chip multi?chip multi adj chip) and mount\$3 near3 board) and	USPĀT;	2004/03/25 16:49
	233	electrode) and interconnect\$3	US-PGPUB;	
		Clothodo) and morronitorio	ЕРО; ЛРО;	
			DERWENT;	
			IBM_TDB	
_	5	((((multi-chip multi?chip multi adj chip) and mount\$3 near3 board) and	USPAT;	2004/03/26 04:42
	1	electrode) and interconnect\$3) and stress near3 relaxat\$3	US-PGPUB;	
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			DERWENT;	
			IBM_TDB	
_	2	("6696765").PN.	USPĀT;	2004/03/26 04:44
		(0050102)	US-PGPUB;	
	!		ЕРО, ЛРО,	
			DERWENT;	
			IBM_TDB	
-	0	10/700470	USPAT;	2004/03/26 04:44
			US-PGPUB;	
ļ		,	ЕРО; ЛРО;	
			DERWENT;	
		·	IBM_TDB	
_	39	(multi-chip multi?chip multi adj chip) and stress near3 relaxat\$3	USPĀT;	2004/03/26 05:10
		r	US-PGPUB;	
	i		ЕРО; ЛРО;	
			DERWENT;	
			IBM TDB	
_	9	(multi-chip multi?chip multi adj chip) and ((stress near3 relaxat\$3) with	USPAT;	2004/03/26 05:17
		thick\$4)	US-PGPUB;	
		**************************************	ЕРО; ЛРО;	
			DERWENT;	
			IBM_TDB	
	9296	(257/779,723,778,747,669,678,737,700,783).CCLS.	USPAT;	2004/03/26 05:17
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			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
	1		11714 1171	<u> </u>

	2896	(438/106,121).CCLS.	USPAT;	2004/03/26 05:17
-	2890	(436/100,121).0055.	US-PGPUB;	2004/03/20 03.17
			ЕРО; ЛРО;	
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			IBM_TDB	
	3	((438/106,121).CCLS.) and ((stress near3 relaxat\$3) with thick\$4)	USPAT;	2004/03/26 05:17
-		((456/100,121).CCES.) and ((sucss near 1 triandles) with thick \$4)	US-PGPUB:	2004/03/20 03.17
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
	19	((257/779,723,778,747,669,678,737,700,783).CCLS.) and ((stress near3	USPAT;	2004/03/26 05:52
-	'	relaxat\$3) with thick\$4)	US-PGPUB;	200 11 05/20 05:52
		1 Claracto) With thick to	ЕРО; ЈРО;	
			DERWENT;	
			IBM_TDB	
_	1		USPAT	2004/03/26 05:45
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_	i		USPAT	2004/03/26 05:46
_	1		USPAT	2004/03/26 05:46
_	1		USPAT	2004/03/26 05:46
1_	1		USPAT	2004/03/26 05:46
_	19	"126044"	USPAT;	2004/03/26 05:53
			US-PGPUB;	
			ЕРО; ЛРО;	
			DERWENT,	
-			IBM_TDB	



	T 1	Document ID	Issue Date	Pages	Title	Current	Cor	Re Inventor	S	C	P 🕽 3	
11	n n US	6710446 B2	20040323	20	Semiconductor device co	257/737	257/	Nagai, Akira et al.	P.	r i	t n c	
12	⊏ 🕫 US	6696765 B2	20040224	14	Multi-chip module	257/779	257/	Kazama, Atsushi e	t P	c)	7 С Г	
13	r 🕫 US	6696764 B2	20040224	30	Flip chip type semicondu	257/778	257/	Honda, Hirokazu	P	r	r r	
14	ггUS	6624504 B1	20030923	43	Semiconductor device an	257/668	257/	Inoue, Kosuke et a], F	r	t r r	
15	ггUS	6621170 B2	20030916	24	Semiconductor device, s	257/783	156/	Yamamoto, Kazun	0 F	r	- r r	
16	r 🔻 US	6396145 B1	20020528	21	Semiconductor device an	257/737	228/	Nagai, Akira et al.	F	r	- r r	
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